

LOW-VOLTAGE 20-BIT BUS SWITCH WITH PRECHARGED OUTPUTS

IDT74CBTLV16800

FEATURES:

- 5Ω A/B bi-directional switch
- **Isolation Under Power-Off Conditions**
- Over-voltage tolerant
- · Latch-up performance exceeds 100mA
- Vcc = 2.3V 3.6V, normal range
- ESD >2000V per MIL-STD-883, Method 3015; >200V using machine model (C = 200pF, R = 0)
- Available in TSSOP and TVSOP packages

APPLICATIONS:

3.3V High Speed Bus Switching and Bus Isolation

DESCRIPTION:

The CBTLV16800 provides 20-bits of high-speed bus switching with low on-state resistance of the switch allowing connections to be made with minimal propagation delay. The device also precharges the B port to a user-selectable bias voltage (BIASV) to minimize live-insertion noise.

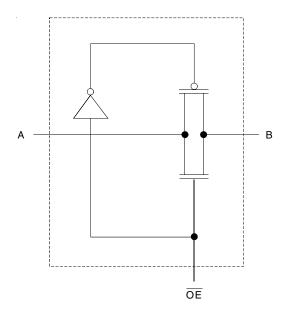
The CBTLV16800 is organized as dual 10-bit bus switches with two different output-enable (\overline{OE}) control inputs. When \overline{OE} is low, the corresponding 10-bit bus switch is on and port A is connected to port B. When $\overline{\mathsf{OE}}$ is high, the switch is open, and a high impedance state exists between the two ports, and port B is precharged to BIASV through the equivalent of a 10-k Ω resistor.

To ensure the high-impedance state during power up or power down, OE should be tied to Vcc through a pullup resistor; the minimum value of the resistor is determined by the current-sinking capability of the driver.

FUNCTIONAL BLOCK DIAGRAM

BIASV 1B1 1B10 2B1 2B10 2A10 20E

SIMPLIFIED SCHEMATIC, EACH **SWITCH**

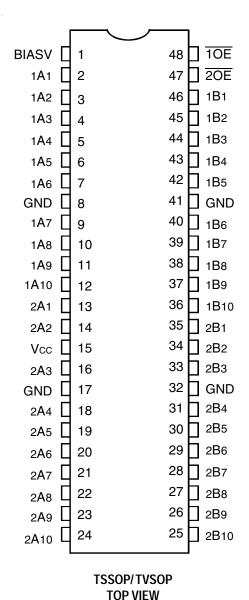


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INDUSTRIAL TEMPERATURE RANGE

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PIN CONFIGURATION



ABSOLUTE MAXIMUM RATINGS(1)

| Symbol | Description | Max. | Unit |
|--------|-------------------------------|-------------|------|
| Vcc | Supply Voltage Range | -0.5 to 4.6 | V |
| BIASV | Bias Voltage Range, Vı | -0.5 to 4.6 | V |
| Vı | Input Voltage Range | -0.5 to 4.6 | V |
| | Continuous Channel Current | 128 | mA |
| lıĸ | Input Clamp Current, VI/O < 0 | – 50 | mA |
| Tstg | Storage Temperature Range | -65 to +150 | °C |

NOTE:

Stresses greater than those listed under ABSOLUTE MAXIMUM RATINGS may cause
permanent damage to the device. This is a stress rating only and functional operation
of the device at these or any other conditions above those indicated in the operational
sections of this specification is not implied. Exposure to absolute maximum rating
conditions for extended periods may affect reliability.

FUNCTION TABLE (EACH 10-BIT BUS SWITCH)⁽¹⁾

| Input OE | Inputs/Outputs |
|----------|-----------------|
| L | A-Port = B-Port |
| Н | A-Port = Z |
| | B-Port = BIASV |

NOTE:

1. H = HIGH Voltage Level

L = LOW Voltage Level

Z = High-Impedance

OPERATING CHARACTERISTICS⁽¹⁾

| Symbol | Parameter | Test Conditions | Min. | Max. | Unit |
|--------|----------------------------------|--------------------|------|------|------|
| Vcc | Supply Voltage | | 2.3 | 3.6 | V |
| BIASV | Bias Voltage | | 1.3 | Vcc | V |
| Vih | High-Level Control Input Voltage | Vcc = 2.3V to 2.7V | 1.7 | _ | V |
| | | Vcc = 2.7V to 3.6V | 2 | _ | |
| VIL | Low-Level Control Input Voltage | Vcc = 2.3V to 2.7V | _ | 0.7 | V |
| | | Vcc = 2.7V to 3.6V | _ | 0.8 | |
| TA | Operating Free-Air Temperature | • | -40 | +85 | °C |

NOTE:

1. All unused control inputs of the device must be held at Vcc or GND to ensure proper device operation.

DC ELECTRICAL CHARACTERISTICS OVER OPERATING RANGE

Following Conditions Apply Unless Otherwise Specified:

Operating Condition: $TA = -40^{\circ}C$ to $+85^{\circ}C$

| Symbol | Parameter | Test Conditions | | Min. | Тур. | Max. | Unit |
|---------------------|--------------------------|---|---------------------------------|------|------|------|------|
| Vik | Control Inputs, Data I/O | Vcc = 3V, II = -18mA | | _ | _ | -1.2 | V |
| lı | Control Inputs | Vcc = 3.6V, Vi = Vcc or GNE |) | _ | _ | ±1 | μA |
| loz | Data I/O | Vcc = 3.6V, Vo = 0V or 3.6V | switch disabled | _ | _ | 5 | μA |
| loff | A Port | Vcc = 0V, Vı or Vo = 0V or 3 | .6V | _ | _ | 10 | μA |
| lo | | Vcc = 3V, BIASV = 2.4V, Vc | $0 = 0$, $\overline{OE} = Vcc$ | 0.25 | _ | _ | mA |
| Icc | | Vcc = 3.6V, Io = 0, VI = Vcc or GND | | _ | _ | 10 | μA |
| ∆lcc ⁽¹⁾ | Control Inputs | Vcc = 3.6V, one input at 3V, other inputs at Vcc or GND | | _ | _ | 300 | μA |
| Сі | Control Inputs | VI = 3V or 0 | | _ | 4 | _ | pF |
| CIO(OFF) | | Vo = 3V or 0, switch off, BIASV = open, \overline{OE} = Vcc | | _ | 6.5 | _ | рF |
| | Vcc = 2.3V | VI = 0 | Iı = 64mA | _ | 5 | 9 | |
| | Typ. at Vcc = 2.5V | | lı = 24mA | _ | 5 | 9 | |
| Ron | | Vı = 1.7V | Iı = 15mA | _ | 25 | 35 | Ω |
| | | VI = 0 | Iı = 64mA | _ | 5 | 7 | |
| | Vcc = 3V | | lı = 24mA | _ | 5 | 7 | |
| | | VI = 2.4V | Iı = 15mA | _ | 10 | 15 | |

NOTES:

- 1. The increase in supply current is attributable to each input that is at the specified voltage level rather than Vcc or GND.
- 2. This is measured by the voltage drop between the A and B terminals at the indicated current through the switch. On-state resistance is determined by the lower of the voltages of the two (A or B) terminals.

SWITCHING CHARACTERISTICS

| | | Vcc = 2. | 5V ± 0.2V | Vcc = 3.3 | 3V ± 0.3V | |
|--------------------------------|-------------------|----------|-----------|-----------|-----------|------|
| Symbol | Parameter | Min. | Max. | Min. | Max. | Unit |
| t _{PD} ⁽¹⁾ | Propagation Delay | _ | 0.15 | _ | 0.25 | ns |
| | A to B or B to A | | | | | |
| tpzh | BIASV = GND | 2.9 | 7.7 | 2.2 | 5.5 | ns |
| | OE to A or B | | | | | |
| tpzL | BIASV = 3V | 2.8 | 6.4 | 2.1 | 5.3 | ns |
| | OE to A or B | | | | | |
| t PHZ | BIASV = GND | 1.4 | 6.8 | 2.6 | 7.6 | ns |
| | OE to A or B | | | | | |
| tplz | BIASV = 3V | 1.3 | 4.2 | 1.5 | 5.1 | ns |
| | OE to A or B | | | | | |

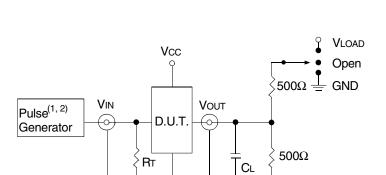
NOTE:

^{1.} The propagation delay is the calculated RC time constant of the typical on-state resistance of the switch and the specified load capacitance when driven by an ideal voltage source (zero output impededance).

TEST CIRCUITS AND WAVEFORMS

TEST CONDITIONS

| Symbol | Vcc ⁽¹⁾ = 3.3V±0.3V | Vcc ⁽²⁾ = 2.5V±0.2V | Unit |
|--------|--------------------------------|--------------------------------|------|
| VLOAD | 6 | 2 x Vcc | V |
| VIH | 3 | Vcc | V |
| VT | 1.5 | Vcc / 2 | V |
| VLZ | 300 | 150 | mV |
| VHZ | 300 | 150 | mV |
| CL | 50 | 30 | pF |



Test Circuits for All Outputs

DEFINITIONS:

 $\ensuremath{\text{CL}}$ = Load capacitance: includes jig and probe capacitance.

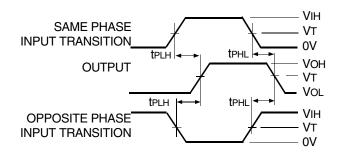
RT = Termination resistance: should be equal to Zout of the Pulse Generator.

NOTES

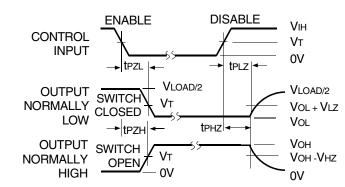
- 1. Pulse Generator for All Pulses: Rate \leq 10MHz; tF \leq 2.5ns; tR \leq 2.5ns.
- 2. Pulse Generator for All Pulses: Rate \leq 10MHz; tF \leq 2ns; tR \leq 2ns.

SWITCH POSITION

| Test | Switch |
|-----------|--------|
| tplz/tpzl | Vload |
| tpнz/tpzн | GND |
| teo | Open |



Propagation Delay

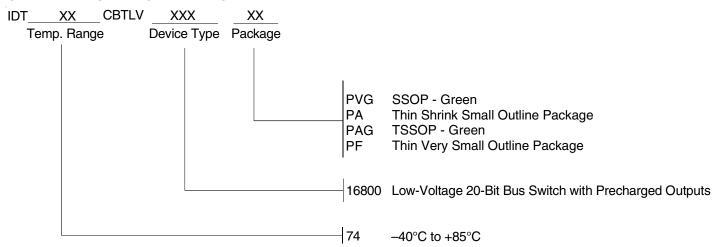


NOTE:

1. Diagram shown for input Control Enable-LOW and input Control Disable-HIGH.

Enable and Disable Times

ORDERING INFORMATION





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